

FCC Test Report

(PART 90S)

Report No.: RF171017C11A-1

FCC ID: WYPPG4032

Test Model: XP8800

Type Number: PG4032/PG4033/PG4034/PG4035/PG4012/PG4041/PG4022

Received Date: Oct. 17, 2017

Test Date: Oct. 21, 2017 ~ Nov. 29, 2017

Issued Date: Dec. 08, 2017

Applicant: Sonim Technologies, Inc.

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Issued By: Bureau Veritas Consumer Products Services (H.K.) Ltd., Taoyuan Branch

Lab Address: No. 47-2, 14th Ling, Chia Pau Vil., Lin Kou Dist., New Taipei City, Taiwan

(R.O.C)

Test Location: No. 19, Hwa Ya 2nd Rd, Wen Hwa Tsuen, Kwei Shan Hsiang, Taoyuan

Hsien 333, Taiwan, R.O.C.

FCC Registration /

788550 / TW0003

Designation Number:





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Report Issue History Record

Issue No.	Description	Date Issued
RF171017C11-1	Original Release	Dec. 04, 2017
RF171017C11A-1	Base the original report "RF171017C11-1" to disable CDMA function.	Dec. 08, 2017



1	Certificate	of Conf	ormity

Product: Mobile Phone

Brand: Sonim

Test Model: XP8800

Sample Status: Production Unit

Applicant: Sonim Technologies, Inc.

Test Date: Oct. 21, 2017 ~ Nov. 29, 2017

Standards: FCC Part 90, Subpart S

The above equipment has been tested by **Bureau Veritas Consumer Products Services (H.K.) Ltd., Taoyuan Branch**, and found compliance with the requirement of the above standards. The test record, data evaluation & Equipment Under Test (EUT) configurations represented herein are true and accurate accounts of the measurements of the sample's EMC characteristics under the conditions specified in this report.

Prepared by :	Cvonne Live	, Date:	Dec. 08, 2017	
_	Evonne Liu / Specialist	_		
	The Cres			
Approved by :		, Date:	Dec. 08, 2017	
_	Dylan Chiou / Project Engineer			



2 Summary of Test Results

	Applied Standard: FCC Part 90 & Part 2					
FCC Clause	Test Item	Result	Remarks			
2.1046 90.635 (b) Effective Radiated Power		Pass	Meet the requirement of limit.			
2.1055 90.213	Frequency Stability	Pass	Meet the requirement of limit.			
2.1049 90.209	Occupied Bandwidth (*)	Pass	Meet the requirement of limit.			
2.1051 90.209	Emission Masks	Pass	Meet the requirement of limit.			
2.1051 90.691	Conducted Spurious Emissions	Pass	Meet the requirement of limit.			
2.1053 90.691	Radiated Spurious Emissions	Pass	Meet the requirement of limit. Minimum passing margin is -0.63 dB at 1586 MHz.			

2.1 Measurement Uncertainty

Where relevant, the following measurement uncertainty levels have been estimated for tests performed on the EUT as specified in CISPR 16-4-2:

Measurement	easurement Frequency	
Conducted Emissions at mains ports	150 kHz ~ 30 MHz	2.44 dB
Redicted Emissions up to 1 CUz	30 MHz ~ 200 MHz	2.93 dB
Radiated Emissions up to 1 GHz	200 MHz ~ 1000 MHz	2.95 dB
Padiated Emissions above 4 CHz	1 GHz ~ 18 GHz	2.26 dB
Radiated Emissions above 1 GHz	18 GHz ~ 40 GHz	1.94 dB



2.2 Test Site and Instruments

Description & Manaufacturer	Model No.	Serial No.	Date of Calibration	Due Date of Calibration
Test Receiver Agilent	N9038A	MY51210203	Feb. 17, 2017	Feb. 16, 2018
Spectrum Analyzer Agilent	N9010A	MY52220314	Dec. 16, 2016	Dec. 15, 2017
Spectrum Analyzer ROHDE & SCHWARZ	FSU43	101261	Dec. 13, 2016	Dec. 12, 2017
BILOG Antenna SCHWARZBECK	VULB9168	9168-472	Dec. 26, 2016	Dec. 27, 2017
HORN Antenna SCHWARZBECK	BBHA 9120 D	9120D-969	Dec. 12, 2016	Dec. 13, 2017
Double Ridge Guide Horn Antenna EMCO	3115	5619	Dec. 26, 2016	Dec. 27, 2017
BILOG Antenna SCHWARZBECK	VULB 9168	9168-153	Dec. 12, 2016	Dec. 13, 2017
Fixed Attenuator Mini-Circuits	MDCS18N-10	MDCS18N-10-01	Apr. 17, 2017	Apr. 16, 2018
MXG Vector signal generator Agilent	N5182B	MY53052282	Dec. 23, 2016	Dec. 22, 2017
Preamplifier EMCI	EMC 012645	980115	Oct. 20, 2017	Oct. 19, 2018
Preamplifier EMCI	EMC 184045	980116	Oct. 20, 2017	Oct. 19, 2018
Preamplifier EMCI	EMC 330H	980112	Oct. 20, 2017	Oct. 19, 2018
Power Meter Anritsu	ML2495A	1145013	Mar. 07, 2017	Mar. 06, 2018
Power Sensor Anritsu	MA2411B	1126085	Mar. 07, 2017	Mar. 06, 2018
RF signal cable HUBER+SUHNNER	SUCOFLEX 104	309219/4 2950114	Oct. 20, 2017	Oct. 19, 2018
RF signal cable HUBER+SUHNNER	SUCOFLEX 104	250130/4	Oct. 20, 2017	Oct. 19, 2018
RF Coaxial Cable Worken	8D-FB	Cable-Ch10-01	Oct. 20, 2017	Oct. 19, 2018
Software BV ADT	E3 6.120103	NA	NA	NA
Antenna Tower MF	MFA-440H	NA	NA	NA
Turn Table MF	MFT-201SS	NA	NA	NA
Antenna Tower &Turn Table Controller MF	MF-7802	NA	NA	NA
Radio Communication Analyzer	MT8820C	6201300640	Aug. 16, 2017	Aug. 15, 2019
Temperature & Humidity Chamber	GTH-120-40-CP-A R	MAA1306-019	Sep. 08, 2017	Sep. 07, 2018
DC Power Supply Topward	33010D	807748	Oct. 25, 2016	Oct. 24, 2018
Digital Multimeter Fluke	87-III	70360742	Jun. 30, 2017	Jun. 29, 2018



ote: 1. The calibration interval of the above test instruments is 12 / 24 months and the calibrations are traceable to NML/ROC and NIST/USA. 2. The test was performed in HwaYa Chamber 10. 3. The horn antenna and preamplifier (model: EMC 184045) are used only for the measurement of		
emission frequency above 1 GHz if tested. 4. The IC Site Registration No. is IC7450F-10.		



3 General Information

3.1 General Description of EUT

Product	Mobile Phone			
Brand	Sonim			
Test Model	XP8800			
Status of EUT	Production Unit			
Dower Supply Dating	5.0 Vdc or 9.0 Vdc or 12.0 Vdc (adapter)			
Power Supply Rating	3.85 Vdc (Li-ion battery)			
Modulation Type	LTE	QPSK, 16QAM, 64QAM		
	LTE Band 14 (Channel Bandwidth: 5 MHz)	790.5 ~ 795.5 MHz		
	LTE Band 14 (Channel Bandwidth: 10 MHz)	793 MHz		
Eraguanay Banga	LTE Band 26 (Channel Bandwidth: 1.4 MHz)	814.7 ~ 823.3 MHz		
Frequency Range	LTE Band 26 (Channel Bandwidth: 3 MHz)	815.5 ~ 822.5 MHz		
	LTE Band 26 (Channel Bandwidth: 5 MHz)	816.5 ~ 821.5 MHz		
	LTE Band 26 (Channel Bandwidth: 10 MHz)	819 MHz		
	LTE Band 14 (Channel Bandwidth: 5 MHz)	4M50W7D		
	LTE Band 14 (Channel Bandwidth: 10 MHz)	8M99W7D		
Emission Designator	LTE Band 26 (Channel Bandwidth: 1.4 MHz)	1M09W7D		
Emission Designator	LTE Band 26 (Channel Bandwidth: 3 MHz)	2M70G7D		
	LTE Band 26 (Channel Bandwidth: 5 MHz)	4M50W7D		
	LTE Band 26 (Channel Bandwidth: 10 MHz)	8M97W7D		
	LTE Band 14 (Channel Bandwidth: 5 MHz)	41.98 mW		
	LTE Band 14 (Channel Bandwidth: 10 MHz)	41.30 mW		
Max. ERP Power	LTE Band 26 (Channel Bandwidth: 1.4 MHz)	51.29 mW		
Wax. ERP Power	LTE Band 26 (Channel Bandwidth: 3 MHz)	50.70 mW		
	LTE Band 26 (Channel Bandwidth: 5 MHz)	51.52 mW		
	LTE Band 26 (Channel Bandwidth: 10 MHz)	52.00 mW		
Antenna Type	Fixed Internal Antenna			
Accessory Device	Device Refer to Note as below			
Data Cable Supplied	Refer to Note as below			

Note:

1. The EUT contains following accessory devices.

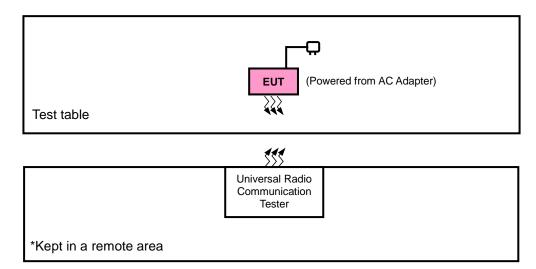
Product	Brand	Model	Description
Adapter	Sonim		I/P: 100-240 Vac, 50/60 Hz, 500 mA O/P: 5 Vdc, 1500 mA or 9 Vdc, 1500 mA or 12 Vdc, 1100 mA
Battery	Sonim	BAT-04900-01S	3.85 Vdc, 4900 mAh
USB Cable 1	N/A	N/A	1.5 m shielded cable w/o core
USB Cable 2	N/A	N/A	1 m non-shielded cable w/o core

2. The above EUT information is declared by manufacturer and for more detailed features description, please refer to the manufacturer's specifications or user's manual.

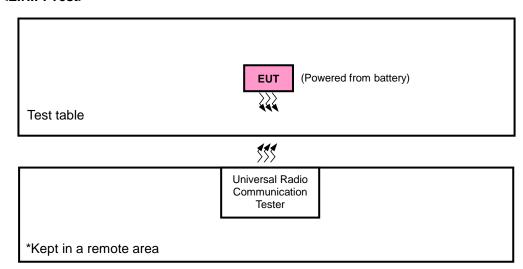


3.2 Configuration of System under Test

<Radiated Emission Test>



<E.R.P. Test>



3.2.1 Description of Support Units

The EUT has been tested as an independent unit together with other necessary accessories or support units.



3.3 Test Mode Applicability and Tested Channel Detail

Pre-Scan has been conducted to determine the worst-case mode from all possible combinations between available modulations, data rates, XYZ axis, and antenna ports

The worst case was found when positioned as the table below. Following channel(s) was (were) selected for the final test as listed below:

Band	ERP	Radiated Emission
LTE Band 14	X-plane	X-axis
LTE Band 26	X-plane	X-axis

LTE Band 14

EUT Configure Mode	Test Item	Available Channel	Tested Channel	Channel Bandwidth	Modulation	Mode
	ERP	23305 to 23355	23305, 23330, 23355	5 MHz	QPSK, 16QAM, 64QAM	1 RB / 0 RB Offset
	LKF	23330	23330	10 MHz	QPSK, 16QAM, 64QAM	1 RB / 24 RB Offset
	Frequency	23305 to 23355	23305, 23330, 23355	5 MHz	QPSK	1 RB / 0 RB Offset
-	Stability	23330	23330	10 MHz	QPSK	1 RB / 24 RB Offset
	Occupied	23305 to 23355	23305, 23330, 23355	5 MHz	QPSK, 16QAM, 64QAM	25 RB / 0 RB Offset
_	Bandwidth	23330	23330	10 MHz	QPSK, 16QAM, 64QAM	50 RB / 0 RB Offset
	Peak to Average Ratio	23305 to 23355	23305, 23330, 23355	5 MHz	QPSK, 16QAM, 64QAM	1 RB / 0 RB Offset
-			23330	23330	10 MHz	QPSK, 16QAM, 64QAM
		23305 to 23355	23305	5 MHz	QPSK	1 RB / 0 RB Offset
						25 RB / 0 RB Offset
				5 MHz	QPSK	1 RB / 24 RB Offset
	Dond Edge				QFSK	25 RB / 0 RB Offset
_	band Edge	Band Edge	23330	10 MHz	QPSK	1 RB / 0 RB Offset
		23330	23330	TO IVII IZ		50 RB / 0 RB Offset
		23330	23330	10 MHz	QPSK	1 RB / 49 RB Offset
			23330	10 IVII IZ	QF SIN	50 RB / 0 RB Offset
	Conducted	23305 to 23355	23305, 23330, 23355	5 MHz	QPSK	1 RB / 0 RB Offset
_	Emission	23330	23330	10 MHz	QPSK	1 RB / 0 RB Offset
_	Radiated	23330	23330	10 MHz	QPSK	1 RB / 24 RB Offset
	Emission	23330	20000	TO IVII IZ	QF3N	1 RB / 50 RB Offset

Note: This device was tested under all bandwidths, RB configurations and modulations. The worst case was found in QPSK modulation.



LTE Band 26

EUT Configure Mode	Test Item	Available Channel	Tested Channel	Channel Bandwidth	Modulation	Mode
		26697 to 26783	26697, 26740, 26783	1.4 MHz	QPSK, 16QAM, 64QAM	1 RB / 2 RB Offset
	ERP	26705 to 26775	26705, 26740, 26775	3 MHz	QPSK, 16QAM, 64QAM	1 RB / 7 RB Offset
_	EKF	26715 to 26765	26715, 26740, 26765	5 MHz	QPSK, 16QAM, 64QAM	1 RB / 12 RB Offset
		26740	26740	10 MHz	QPSK, 16QAM, 64QAM	1 RB / 49 RB Offset
		26697 to 26783	26697, 26783	1.4 MHz	QPSK	1 RB / 2 RB Offset
	Frequency	26705 to 26775	26705, 26775	3 MHz	QPSK	1 RB / 7 RB Offset
· -	Stability	26715 to 26765	26715, 26765	5 MHz	QPSK	1 RB / 12 RB Offset
		26740	26740	10 MHz	QPSK	1 RB / 49 RB Offset
		26697 to 26783	26697, 26740, 26783	1.4 MHz	QPSK, 16QAM, 64QAM	6 RB / 0 RB Offset
	Occupied	26705 to 26775	26705, 26740, 26775	3 MHz	QPSK, 16QAM, 64QAM	15 RB / 0 RB Offset
-	Bandwidth	26715 to 26765	26715, 26740, 26765	5 MHz	QPSK, 16QAM, 64QAM	25 RB / 0 RB Offset
		26740	26740	10 MHz	QPSK, 16QAM, 64QAM	50 RB / 0 RB Offset
		26697 to 26783	26697, 26740, 26783	1.4 MHz	QPSK, 16QAM, 64QAM	6 RB / 0 RB Offset
	Emission	26705 to 26775	26705, 26740, 26775	3 MHz	QPSK, 16QAM, 64QAM	15 RB / 0 RB Offset
-	Mask	26715 to 26765	26715, 26740, 26765	5 MHz	QPSK, 16QAM, 64QAM	25 RB / 0 RB Offset
		26740	26740	10 MHz	QPSK, 16QAM, 64QAM	50 RB / 0 RB Offset
		26697 to 26783	26697, 26740, 26783	1.4 MHz	QPSK	1 RB / 0 RB Offset
	Conducted	26705 to 26775	26705, 26740, 26775	3 MHz	QPSK	1 RB / 0 RB Offset
_	Emission	26715 to 26765	26715, 26740, 26765	5 MHz	QPSK	1 RB / 0 RB Offset
		26740	26740	10 MHz	QPSK	1 RB / 0 RB Offset
-	Radiated Emission	26740	26740	10 MHz	QPSK	1 RB / 49 RB Offset

Note: This device was tested under all bandwidths, RB configurations and modulations. The worst case was found in QPSK modulation.

Test Condition:

100t Odilattioni			
Test Item	Environmental Conditions	Input Power	Tested By
ERP	25 deg. C, 65 % RH	3.85 Vdc	Getaz Yang
Frequency Stability	25 deg. C, 65 % RH	3.85 Vdc	Gavin Wu
Occupied Bandwidth	25 deg. C, 65 % RH	3.85 Vdc	Gavin Wu
Peak to Average Ratio	25 deg. C, 65 % RH	3.85 Vdc	Gavin Wu
Emission Mask	25 deg. C, 65 % RH	3.85 Vdc	Gavin Wu
Condcudeted Emission	25 deg. C, 65 % RH	3.85 Vdc	Gavin Wu
Radiated Emission	25 deg. C, 65 % RH	120 Vac, 60 Hz	Getaz Yang



3.4 **EUT Operating Conditions**

The EUT makes a call to the communication simulator. The communication simulator station system controlled a EUT to export maximum output power under transmission mode and specific channel frequency

3.5 **General Description of Applied Standards**

The EUT is a RF Product. According to the specifications of the manufacturer, it must comply with the

requirements of the following standards: FCC 47 CFR Part 2 FCC 47 CFR Part 90 ANSI/TIA/EIA-603-E 2016 ANSI 63.26-2015 **Note:** All test items have been performed and recorded as per the above standards.



4 Test Types and Results

4.1 Output Power Measurement

4.1.1 Limits of Output Power Measurement

Mobile / Portable station are limited to 100 watts e.r.p.

4.1.2 Test Procedures

EIRP / ERP Measurement:

- a. All measurements were done at low, middle and high operational frequency range. RBW and VBW is 5 MHz for CDMA and 10 MHz for LTE mode.
- b. Substitution method is used for E.I.R.P measurement. In the semi-anechoic chamber, EUT placed on the 0.8 m (below or equal 1 GHz) and/or 1.5 m (above 1 GHz) height of Turn Table, rotated the table around 360 degrees to search the maximum radiation power and receiver antenna shall be rotated vertical and horizontal polarization and moved height from 1 m to 4 m to find the maximum polar radiated power. The "Read Value" is the spectrum reading the maximum power value.
- c. The substitution horn antenna is substituted for EUT at the same position and signals generator export the CW signal to the substitution antenna via a tx cable. Rotated the Turn Table and moved receiving antenna to find the maximum radiation power. Adjust output power level of S.G to get a Value of spectrum reading equal to "Read Value" of step b. Record the power level of S.G.
- d. EIRP = Output power level of S.G TX cable loss + Antenna gain of substitution horn.E.R.P power can be calculated form E.I.R.P power by subtracting the gain of dipole, E.R.P power = E.I.P.R power 2.15 dBi.

Conducted Power Measurement:

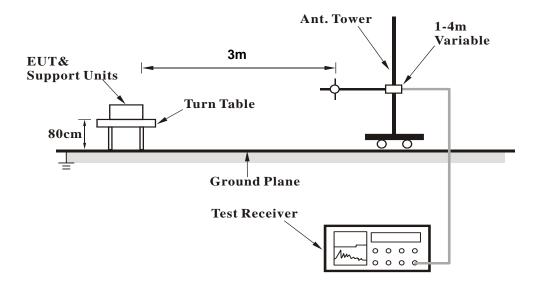
- a. The EUT was set up for the maximum power with LTE link data modulation and link up with simulator.
- b. Set the EUT to transmit under low, middle and high channel and record the power level shown on simulator.



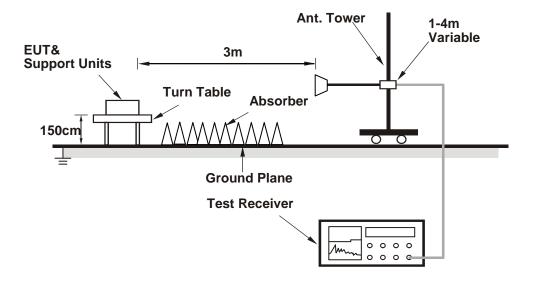
4.1.3 Test Setup

EIRP / ERP Measurement:

<Radiated Emission below or equal 1 GHz>



<Radiated Emission above 1 GHz>



For the actual test configuration, please refer to the attached file (Test Setup Photo).

Conducted Power Measurement:





4.1.4 Test Results

Conducted Output Power (dBm)

						L	TE Ban	d 14						
				QP	SK				QAM		64QAM			
BW (MHz)	RB Size	RB Offset		Mid Ch 23330		3GPP MPR		Mid Ch 23330		3GPP MPR		Mid Ch 23330		3GPP MPR
(11112)	OIZ6	Oliset		793.0 MHz		(dB)		793.0 MHz		(dB)		793.0 MHz		(dB)
	1	0		23.24		0		22.32		1		21.53		2
	1	24		23.21		0		22.28		1		21.46		2
	1	49	23.17 0			0		22.25		1		21.41		2
10	25	0		22.37		1		21.31		2		20.39		3
	25	12		22.34		1		21.28		2	20.35		3	
	25	25		22.30		1		21.24		2		20.32		3
	50	0		22.34		1		21.31		2		20.37		3
					SK			16QAM					QAM	
BW (MHz)	RB Size	RB Offset	Low Ch 23305	Mid Ch 23330	High Ch 23355	3GPP MPR	Low Ch 23305	Mid Ch 23330	High Ch 23355	3GPP MPR	Low Ch 23305	Mid Ch 23330	High Ch 23355	3GPP MPR
(11112)	O IZE	Oliset	790.5 MHz	793.0 MHz	795.5 MHz	(dB)	790.5 MHz	793.0 MHz	795.5 MHz	(dB)	790.5 MHz	793.0 MHz	795.5 MHz	(dB)
	1	0	23.15	23.19	23.21	0	22.23	22.27	22.29	1	21.45	21.49	21.51	2
	1	12	23.12	23.16	23.18	0	22.19	22.23	22.25	1	21.38	21.42	21.44	2
	1	24	23.08	23.12	23.14	0	22.16	22.20	22.22	1	21.33	21.37	21.39	2
5	12	0	22.28	22.32	22.34	1	21.22	21.26	21.28	2	21.44	21.48	21.50	3
	12	6	22.25	22.29	22.31	1	21.19	21.23	21.25	2	21.37	21.41	21.43	3
	12	13	22.21	22.25	22.27	1	21.15	21.19	21.21	2	21.32	21.36	21.38	3
	25	0	22.25	22.29	22.31	1	21.22	21.26	21.28	2	20.29	20.33	20.35	3

							LTE Ba	nd 26						
					SK				QAM				QAM	
BW (MHz)	RB Size	RB Offset		Mid Ch 26740 819.0 MHz		3GPP MPR (dB)		Mid Ch 26740 819.0 MHz		3GPP MPR (dB)		Mid Ch 26740 819.0 MHz		3GPP MPR (dB)
	1	0		23.98		0		23.13		1		21.86		2
i	1	24		23.92		0		23.10		1		21.82		2
i	1	49		23.91		0		23.07		1		21.76		2
10	25	0		23.08		1		22.06		2		21.16		3
1	25	12		23.04		1		22.03		2		21.13		3
i	25	25		23.02		1		22.01		2		21.10		3
İ	50	0		23.00		1		21.99		2		21.13		3
				QP	SK			160	QAM			640	QAM	
BW (MHz)	RB Size	RB Offset	Low Ch 26715 816.5	Mid Ch 26740 819.0	High Ch 26765 821.5	3GPP MPR	Low Ch 26715 816.5	Mid Ch 26740 819.0	High Ch 26765 821.5	3GPP MPR	Low Ch 26715 816.5	Mid Ch 26740 819.0	High Ch 26765 821.5	3GPP MPR
			MHz	MHz	MHz	(dB)	MHz	MHz	MHz	(dB)	MHz	MHz	MHz	(dB)
	1	0	24.10	23.95	24.08	0	23.25	23.10	23.23	1	21.97	21.82	21.95	2
ı	1	12	24.04	23.89	24.02	0	23.22	23.07	23.20	1	21.93	21.78	21.91	2
i	1	24	24.03	23.88	24.01	0	23.19	23.04	23.17	1	21.87	21.72	21.85	2
5	12	0	23.20	23.05	23.18	1	22.18	22.03	22.16	2	21.96	21.81	21.94	3
ı	12	6	23.16	23.01	23.14	1	22.15	22.00	22.13	2	21.92	21.77	21.90	3
i	12	13	23.14	22.99	23.12	1	22.13	21.98	22.11	2	21.86	21.71	21.84	3
i	25	0	23.12	22.97	23.10	1	22.11	21.96	22.09	2	21.24	21.09	21.22	3
				QP	SK			160	QAM			640	QAM	
BW (MHz)	RB Size	RB Offset	Low Ch 26705	Mid CH 26740	High CH 26775	3GPP MPR	Low Ch 26705	Mid CH 26740	High CH 26775	3GPP MPR	Low Ch 26705	Mid CH 26740	High CH 26775	3GPP MPR
(12)			815.5 MHz	819.0 MHz	822.5 MHz	(dB)	815.5 MHz	819.0 MHz	822.5 MHz	(dB)	815.5 MHz	819.0 MHz	822.5 MHz	(dB)
ı	1	0	24.07	23.92	24.05	0	23.22	23.07	23.20	1	21.93	21.78	21.91	2
İ	1	7	24.01	23.86	23.99	0	23.19	23.04	23.17	1	21.89	21.74	21.87	2
1 _	1	14	24.00	23.85	23.98	0	23.16	23.01	23.14	1	21.83	21.68	21.81	2
3	8	0	23.17	23.02	23.15	1	22.15	22.00	22.13	2	21.92	21.77	21.90	3
İ	8	3	23.13	22.98	23.11	1	22.12	21.97	22.10	2	21.88	21.73	21.86	3
İ	8	7	23.11	22.96	23.09	1	22.10	21.95	22.08	2	21.82	21.67	21.80	3
	15	0	23.09	22.94	23.07	1	22.08	21.93	22.06	2	21.20	21.05	21.18	3
i i			Low Ch	QP Mid Ch	SK High Ch	1	Low Ch	Mid Ch	QAM Hiah Ch		Low Ch	Mid Ch	QAM	
BW	RB	RB	26697	26740	26783	3GPP	26697	26740	26783	3GPP	26697	26740	High Ch 26783	3GPP
(MHz)	Size	Offset	814.7 MHz	819.0 MHz	823.3 MHz	MPR (dB)	814.7 MHz	819.0 MHz	823.3 MHz	MPR (dB)	814.7 MHz	819.0 MHz	823.3 MHz	MPR (dB)
	1	0	24.03	23.88	24.01	0	23.18	23.03	23.16	1	21.89	21.74	21.87	2
1	1	2	23.97	23.82	23.95	0	23.15	23.00	23.13	1	21.85	21.70	21.83	2
1	1	5	23.96	23.81	23.94	0	23.12	22.97	23.10	1	21.79	21.64	21.77	2
1		0	24.01	23.86	23.99	0	23.17	23.02	23.15	1	21.88	21.73	21.86	2
1.4	3	U												1
1.4	3	1	23.95	23.80	23.93	0	23.14	22.99	23.12	1	21.84	21.69	21.82	2
1.4				23.80 23.79	23.93 23.92	0	23.14 23.11	22.99 22.96	23.12 23.09	1	21.84 21.78	21.69 21.63	21.82 21.76	2



ERP Power (dBm)

	` '			LTE Band 14			
			Channel Ba	ndwidth: 5 MHz	/ QPSK		
Plane	Channel	Frequency (MHz)	LVL (dBm)	Correction Factor (dB)	ERP (dBm)	ERP (mW)	Polarization (H/V)
	23305	790.5	-14.02	32.18	16.01	39.90	
	23330	793.0	-13.98	32.17	16.04	40.18	Н
X	23355	795.5	-13.88	32.26	16.23	41.98	
^	23305	790.5	-16.60	32.69	13.94	24.77	
	23330	793.0	-16.52	32.72	14.05	25.41	V
	23355	795.5	-16.59	32.85	14.11	25.76	
			Channel Ba	ndwidth: 5 MHz	/ 16QAM		
	23305	790.5	-14.08	32.18	15.95	39.36	
	23330	793.0	-14.11	32.17	15.91	38.99	Н
X	23355	795.5	-14.13	32.26	15.98	39.63	
^	23305	790.5	-16.92	32.69	13.62	23.01	
	23330	793.0	-16.88	32.72	13.69	23.39	V
	23355	795.5	-17.02	32.85	13.68	23.33	
			Channel Ba	ndwidth: 5 MHz	64QAM		
	23305	790.5	-14.38	32.18	15.65	36.73	
	23330	793.0	-14.41	32.17	15.61	36.39	Н
X	23355	795.5	-14.43	32.26	15.68	36.98	
_ ^	23305	790.5	-17.22	32.69	13.32	21.48	
	23330	793.0	-17.18	32.72	13.39	21.83	V
	23355	795.5	-17.32	32.85	13.38	21.78	

				LTE Band 14								
	Channel Bandwidth: 10 MHz / QPSK											
Plane	Channel	Frequency (MHz)	LVL (dBm)	Correction Factor (dB)	ERP (dBm)	ERP (mW)	Polarization (H/V)					
Х	23330	793.0	-13.86	32.17	16.16	41.30	Н					
^	23330	793.0	-16.59	32.72	13.98	25.00	V					
		(Channel Bar	ndwidth: 10 MHz	/ 16QAM							
Х	23330	793.0	-13.96	32.17	16.06	40.36	Н					
^	23330	793.0	-16.66	32.72	13.91	24.60	V					
		(Channel Bar	ndwidth: 10 MHz	/ 64QAM							
Х	23330	793.0	-14.26	32.17	15.76	37.67	Н					
^	23330	793.0	-16.96	32.72	13.61	22.96	V					



				LTE Band 26								
	Channel Bandwidth: 1.4 MHz / QPSK											
Plane	Channel	Frequency (MHz)	LVL (dBm)	Correction Factor (dB)	ERP (dBm)	ERP (mW)	Polarization (H/V)					
	26697	814.7	-13.11	32.01	16.75	47.32						
	26740	819.0	-13.00	32.11	16.96	49.66	Н					
X	26783	823.3	-13.07	32.32	17.10	51.29						
_ ^	26697	814.7	-17.14	32.54	13.25	21.13						
	26740	819.0	-17.06	32.51	13.30	21.38	V					
	26783	823.3	-17.15	32.51	13.21	20.94						
		C	hannel Ban	dwidth: 1.4 MHz	/ 16QAM							
	26697	814.7	-13.92	32.01	15.94	39.26						
	26740	819.0	-13.77	32.11	16.19	41.59	Н					
	26783	823.3	-13.86	32.32	16.31	42.76						
X	26697	814.7	-17.55	32.54	12.84	19.23						
	26740	819.0	-17.20	32.51	13.16	20.70	V					
	26783	823.3	-17.26	32.51	13.10	20.42						
		C	hannel Ban	dwidth: 1.4 MHz	/ 64QAM							
	26697	814.7	-14.22	32.01	15.64	36.64						
	26740	819.0	-14.07	32.11	15.89	38.82	Н					
	26783	823.3	-14.06	32.32	16.11	40.83						
X	26697	814.7	-17.75	32.54	12.64	18.37						
	26740	819.0	-17.50	32.51	12.86	19.32	V					
	26783	823.3	-17.56	32.51	12.80	19.05						



				LTE Band 26								
	Channel Bandwidth: 3 MHz / QPSK											
Plane	Channel	Frequency (MHz)	LVL (dBm)	Correction Factor (dB)	ERP (dBm)	ERP (mW)	Polarization (H/V)					
	26705	815.5	-12.98	32.02	16.89	48.87						
	26740	819.0	-12.91	32.11	17.05	50.70	Н					
Х	26775	822.5	-13.00	32.18	17.03	50.47						
^	26705	815.5	-17.10	32.5	13.25	21.13						
	26740	819.0	-16.97	32.51	13.39	21.83	V					
	26775	822.5	-17.06	32.47	13.26	21.18						
			Channel Ba	ndwidth: 3 MHz	/ 16QAM							
	26705	815.5	-13.72	32.02	16.15	41.21						
	26740	819.0	-13.54	32.11	16.42	43.85	Н					
Х	26775	822.5	-13.69	32.18	16.34	43.05						
^	26705	815.5	-17.11	32.5	13.24	21.09						
	26740	819.0	-17.02	32.51	13.34	21.58	V					
	26775	822.5	-17.05	32.47	13.27	21.23						
			Channel Ba	ndwidth: 3 MHz	/ 64QAM							
	26705	815.5	-14.02	32.02	15.85	38.46						
	26740	819.0	-13.74	32.11	16.22	41.88	Н					
X	26775	822.5	-13.99	32.18	16.04	40.18						
^	26705	815.5	-17.41	32.5	12.94	19.68						
	26740	819.0	-17.32	32.51	13.04	20.14	V					
	26775	822.5	-17.35	32.47	12.97	19.82						



				LTE Band 26								
	Channel Bandwidth: 5 MHz / QPSK											
Plane	Channel	Frequency (MHz)	LVL (dBm)	Correction Factor (dB)	ERP (dBm)	ERP (mW)	Polarization (H/V)					
	26715	816.5	-12.88	32.04	17.01	50.23						
	26740	819.0	-12.84	32.11	17.12	51.52	Н					
X	26765	821.5	-12.89	31.79	16.75	47.32						
^	26715	816.5	-16.91	32.52	13.46	22.18						
	26740	819.0	-16.84	32.51	13.52	22.49	V					
	26765	821.5	-16.33	32.17	13.69	23.39						
			Channel Ba	ndwidth: 5 MHz	/ 16QAM							
	26715	816.5	-13.11	32.04	16.78	47.64						
	26740	819.0	-13.32	32.11	16.64	46.13	Н					
Х	26765	821.5	-13.54	31.79	16.10	40.74						
^	26715	816.5	-16.84	32.52	13.53	22.54						
	26740	819.0	-16.94	32.51	13.42	21.98	V					
	26765	821.5	-16.97	32.17	13.05	20.18						
			Channel Ba	ndwidth: 5 MHz	/ 64QAM							
	26715	816.5	-13.41	32.04	16.48	44.46						
	26740	819.0	-13.62	32.11	16.34	43.05	Н					
X	26765	821.5	-13.74	31.79	15.90	38.90						
^	26715	816.5	-17.14	32.52	13.23	21.04						
	26740	819.0	-17.14	32.51	13.22	20.99	V					
	26765	821.5	-17.27	32.17	12.75	18.84						

	LTE Band 26											
	Channel Bandwidth: 10 MHz / QPSK											
Plane	Channel	Frequency (MHz)	LVL (dBm)	Correction Factor (dB)	ERP (dBm)	ERP (mW)	Polarization (H/V)					
Х	26740	819.0	-12.80	32.11	17.16	52.00	Н					
^	26740	819.0	-16.30	32.51	14.06	25.47	V					
		(Channel Bar	ndwidth: 10 MHz	/ 16QAM							
	26740	819.0	-13.32	32.11	16.64	46.13	Н					
Х	26740	819.0	-16.86	32.51	13.50	22.39	V					
		(Channel Bar	ndwidth: 10 MHz	/ 64QAM							
Х	26740	819.0	-13.62	32.11	16.34	43.05	Н					
^	26740	819.0	-17.16	32.51	13.20	20.89	V					



4.2 Frequency Stability Measurement

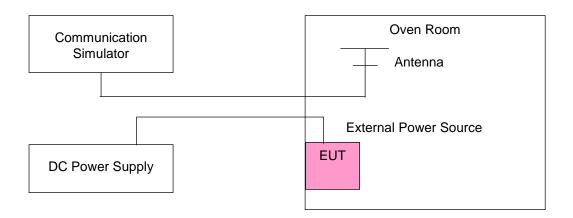
- 4.2.1 Limits of Frequency Stability Measurement
- 1.5 ppm is for base and fixed station. 2.5 ppm is for mobile station.

4.2.2 Test Procedure

- a. Device is placed at the oven room. The oven room could control the temperatures and humidity. Power warm up is at least 15 min and power applied should perform before recording frequency error.
- b. EUT is connected the external power supply to control the DC input power. The test voltage range is from minimum to maximum working voltage. Each step shall be record the frequency error rate.
- c. The temperature range step is 10 degrees in this test items. All temperature levels shall be hold the ± 0.5 $^{\circ}$ C during the measurement testing. The each temperature step shall be at least 0.5 hours, consider the EUT could be test under the stability condition.

NOTE: The frequency error was recorded frequency error from the communication simulator.

4.2.3 Test Setup





4.2.4 Test Results

Frequency Error vs. Voltage

Voltage		Channel Bandwidth: 5 MHz							
(Volts)	Low C	Low Channel High Channel							
	Frequency (MHz)	Frequency Error (ppm)	Frequency (MHz)	Frequency Error (ppm)					
3.8	790.500003	0.003	795.500004	0.005	2.5				
3.6	790.500004	0.005	795.500003	0.004	2.5				
4.35	790.500002	0.003	795.500003	0.004	2.5				

Note: The applicant defined the normal working voltage of the battery is from 3.6 Vdc to 4.35 Vdc.

	·	LTE B	and 14		
Temp. (℃)	Low C	hannel	High C	hannel	Limit (ppm)
	Frequency (MHz)				
-30	790.500001	0.001	795.500002	0.003	2.5
-20	790.500002	0.003	795.500003	0.004	2.5
-10	790.500002	0.002	795.500002	0.003	2.5
0	790.500003	0.004	795.500003	0.004	2.5
10	790.500002	0.002	795.500004	0.005	2.5
20	790.499998	-0.003	795.499997	-0.004	2.5
30	790.499999	-0.002	795.499997	-0.004	2.5
40	790.499998	-0.002	795.499996	-0.005	2.5
50	790.499999	-0.001	795.499996	-0.005	2.5



	LTE Ba		
Voltage (Volts)	Channel Band	Limit (ppm)	
(VOILS)	Frequency (MHz)	Frequency Error (ppm)	
3.8	793.000001	0.001	2.5
3.6	793.000004	0.005	2.5
4.35	793.000001	0.001	2.5

Note: The applicant defined the normal working voltage of the battery is from 3.6 Vdc to 4.35 Vdc.

	LTE B							
Temp. (°C)	Channel Band	Channel Bandwidth: 10 MHz						
	Frequency (MHz)	Frequency Error (ppm)						
-30	793.000002	0.002	2.5					
-20	793.000002	0.003	2.5					
-10	793.000002	0.003	2.5					
0	793.000002	0.003	2.5					
10	793.000002	0.003	2.5					
20	792.999997	-0.003	2.5					
30	792.999999	-0.002	2.5					
40	792.999999	-0.002	2.5					
50	792.999996	-0.005	2.5					



Voltage		Channel Bandwidth: 1.4 MHz								
(Volts)	Low C	hannel	High C	hannel	Limit (ppm)					
	Frequency (MHz)	Frequency Error (ppm)	Frequency (MHz)	Frequency Error (ppm)						
3.8	814.700001	0.001	823.300002	0.003	2.5					
3.6	814.700001	0.001	823.300003	0.004	2.5					
4.35	814.700002	0.002	823.300002	0.002	2.5					

Note: The applicant defined the normal working voltage of the battery is from 3.6 Vdc to 4.35 Vdc.

- 11-1	or vs. remperature	LTE Band 26							
		Channel Band	width: 1.4 MHz						
Temp. (°C)	Low C	hannel	High C	hannel	Limit (ppm)				
	Frequency (MHz) Frequency Error (ppm)		Frequency (MHz)	requency (MHz) Frequency Error (ppm)					
-30	814.700003	0.003	823.300003	0.003	2.5				
-20	814.700002	0.002	823.300004	0.004	2.5				
-10	814.700002	0.002	823.300002	0.002	2.5				
0	814.700003	0.004	823.300004	0.004	2.5				
10	814.700002	0.002	823.300003	0.003	2.5				
20	814.699996	-0.005	823.299999	-0.001	2.5				
30	814.699997	-0.004	823.299997	-0.004	2.5				
40	814.699998	-0.003	823.299996	-0.005	2.5				
50	814.699998	-0.003	823.299997	-0.003	2.5				



Voltage		Channel Band	dwidth: 3 MHz		
(Volts)	Low C	hannel	High C	hannel	Limit (ppm)
	Frequency (MHz)	Frequency Error (ppm)	Frequency (MHz)	Frequency Error (ppm)	
3.8	815.500003	0.004	822.500003	0.003	2.5
3.6	815.500002	0.003	822.500002	0.002	2.5
4.35	815.500002	0.003	822.500002	0.003	2.5

Note: The applicant defined the normal working voltage of the battery is from 3.6 Vdc to 4.35 Vdc.

	or vs. remperature	LTE Band 26							
	Channel Bandwidth: 3 MHz								
Temp. (℃)	Low C	hannel	High C	hannel	Limit (ppm)				
	Frequency (MHz)	Frequency Error (ppm)	Frequency (MHz)	Frequency Error (ppm)					
-30	815.500003	0.004	822.500002	0.002	2.5				
-20	815.500003	0.004	822.500003	0.004	2.5				
-10	815.500004	0.004	822.500001	0.002	2.5				
0	815.500002	0.003	822.500003	0.003	2.5				
10	815.500004	0.004	822.500002	0.002	2.5				
20	815.499996	-0.005	822.499999	-0.002	2.5				
30	815.499999	-0.001	822.499996	-0.005	2.5				
40	815.499996	-0.005	822.499998	-0.003	2.5				
50	815.499999	-0.001	822.499996	-0.004	2.5				



Voltage		Channel Bandwidth: 5 MHz							
(Volts)	Low C	hannel	High C	hannel	Limit (ppm)				
	Frequency (MHz)	Frequency Error (ppm)	Frequency (MHz)	Frequency Error (ppm)					
3.8	816.500004	0.005	821.500000	0.000	2.5				
3.6	816.500003	0.003	821.500000	0.000	2.5				
4.35	816.500003	0.004	821.500000	0.000	2.5				

Note: The applicant defined the normal working voltage of the battery is from 3.6 Vdc to 4.35 Vdc.

Frequency En	LTE Band 26								
		Channel Band	dwidth: 5 MHz						
Temp. (°C)	Low C	hannel	High C	hannel	Limit (ppm)				
	Frequency (MHz)	Frequency Error (ppm)	Frequency (MHz)	Frequency Error (ppm)					
-30	816.500003	0.004	821.500003	0.003	2.5				
-20	816.500003	0.003	821.500001	0.002	2.5				
-10	816.500002	0.003	821.500002	0.002	2.5				
0	816.500002	0.003	821.500002	0.002	2.5				
10	816.500003	0.004	821.500002	0.003	2.5				
20	816.499996	-0.004	821.499996	-0.005	2.5				
30	816.499997	-0.003	821.499999	-0.002	2.5				
40	816.499997	-0.004	821.499999	-0.002	2.5				
50	816.499997	-0.004	821.499997	-0.003	2.5				



	LTE B		
Voltage (Volts)	Channel Band	Limit (ppm)	
(VOIIS)	Frequency (MHz)	Frequency Error (ppm)	
3.8	819.000003	0.003	2.5
3.6	819.000002	0.002	2.5
4.35	819.000004	0.005	2.5

Note: The applicant defined the normal working voltage of the battery is from 3.6 Vdc to 4.35 Vdc.

	LTE B		
Temp. (℃)	Channel Band	Limit (ppm)	
	Frequency (MHz)	Frequency Error (ppm)	
-30	819.000002	0.002	2.5
-20	819.000003	0.003	2.5
-10	819.000001	0.002	2.5
0	819.000003	0.003	2.5
10	819.000003	0.004	2.5
20	818.999998	-0.003	2.5
30	818.999997	-0.004	2.5
40	818.999996	-0.005	2.5
50	818.999999	-0.001	2.5

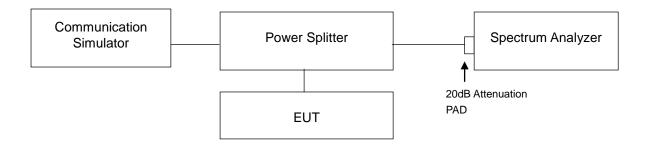


4.3 Occupied Bandwidth Measurement

4.3.1 Test Procedure

The EUT makes a call to the communication simulator. All measurements were done at low, middle and high operational frequency range. The communication simulator station system controlled a EUT to export maximum output power under transmission mode and specific channel frequency. Use OBW measurement function of Spectrum analyzer to measure 99 % occupied bandwidth.

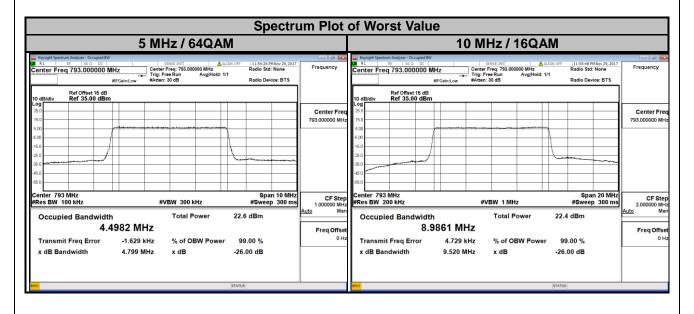
4.3.2 Test Setup





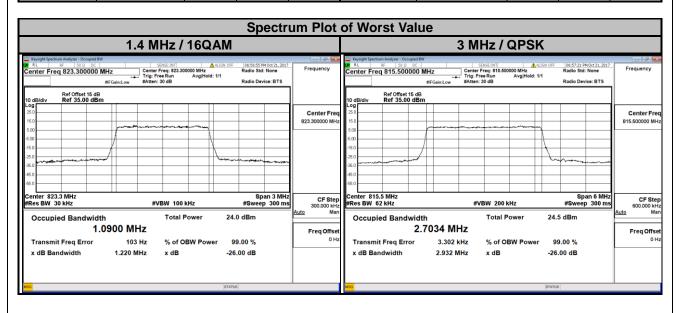
4.3.3 Test Result

LTE Band 14											
(Channel Band	dwidth: 5	MHz		C	hannel Band	width: 1	0 MHz			
Channel	Frequency (MHz)	99 % Occupie Bandwidth (MF				Channel Frequency		% Occup dwidth (I			
		QPSK	16QAM	64QAM		(MHz)	QPSK	16QAM	64QAM		
23205	779.5	4.4906	4.4912	4.4941		782.0					
23230	782.0	4.4939	4.4960	4.4982	23230		8.9838	8.9853	8.9861		
23255	784.5	4.4932	4.4959	4.4943							



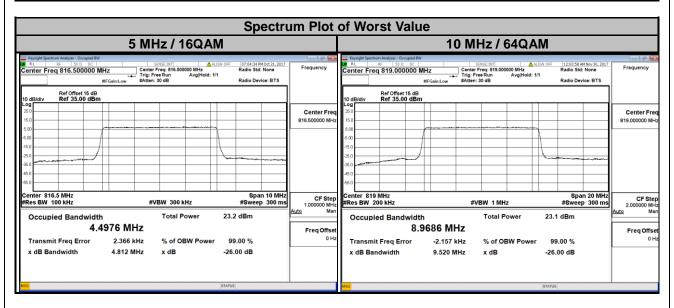


LTE Band 26											
С	hannel Bandv	vidth: 1.4	4 MHz			Channel Band	width: 3	MHz			
Channel	Frequency		99 % Occupied Bandwidth (MHz)		Channel	Frequency		% Occup dwidth (I			
	(MHz)	QPSK	16QAM	64QAM		(MHz)	QPSK	16QAM	64QAM		
26697	814.7	1.0865	1.0899	1.0894	26705	815.5	2.7034	2.6989	2.6995		
26740	819.0	1.0864	1.0885	1.0897	26740	819.0	2.7026	2.6968	2.6965		
26783	823.3	1.0866	1.0900	1.0897	26775	822.5	2.7022	2.6981	2.6978		





LTE Band 26									
Channel Bandwidth: 5 MHz					Channel Bandwidth: 10 MHz				
Channel	Frequency (MHz)	99 % Occupied Bandwidth (MHz)			Channel	Frequency	99 % Occupied Bandwidth (MHz)		
		QPSK	16QAM	64QAM		(MHz)	QPSK	16QAM	64QAM
26715	816.5	4.4931	4.4976	4.4957	26740	819.0	8.9606	8.9639	8.9686
26740	819.0	4.4894	4.4939	4.4929					
26765	821.5	4.4904	4.4937	4.4913					



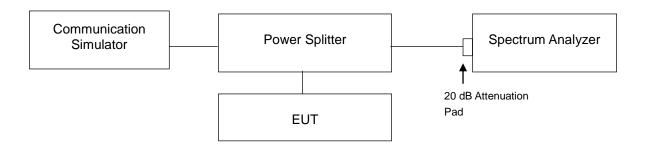


4.4 Emission Mask Measurement

4.4.1 Limits of Band Edge Measurement

According to FCC part 90.691 shall be tested the emission mask. For any frequency removed from the EA licensee's frequency block by up to and including 37.5 kHz, the power of any emission shall be attenuated below the transmitter power (P) in watts by at least 116 Log10(f/6.1) decibels or 50+10Log10(P) decibels or 80 decibels, whichever is the lesser attenuation, where f is the frequency removed from the center of the outer channel in the block in kilohertz and where f is greater than 12.5 kHz.

4.4.2 Test Setup

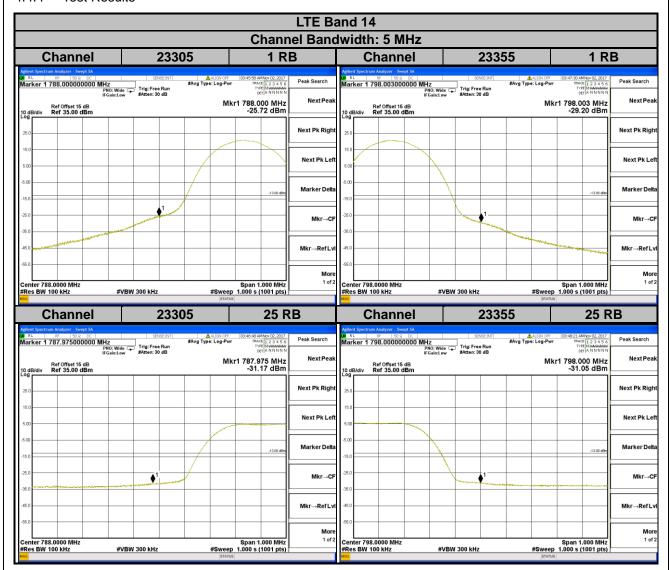


4.4.3 Test Procedures

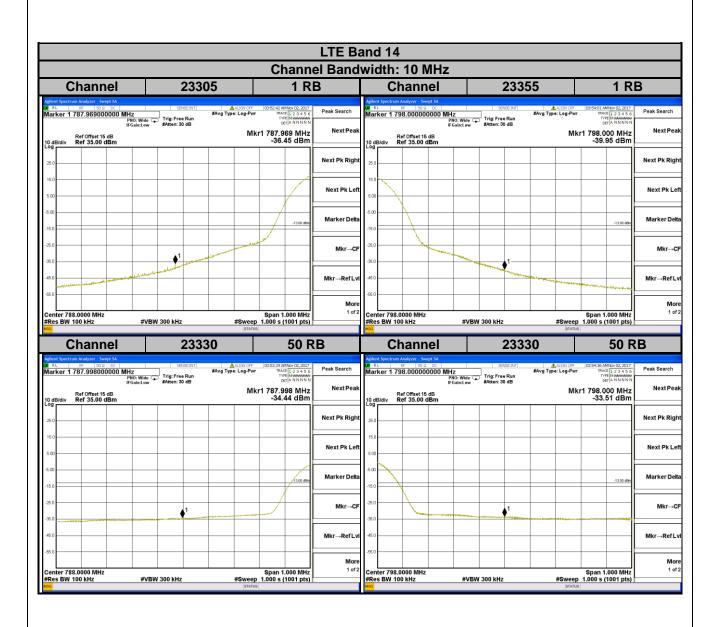
- a. The measurement used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.
- b. Record the test plot.



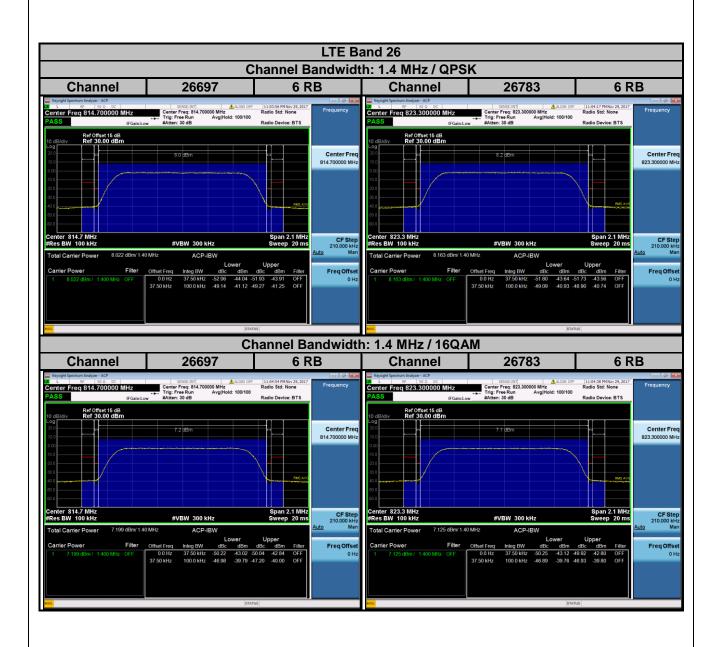
4.4.4 Test Results



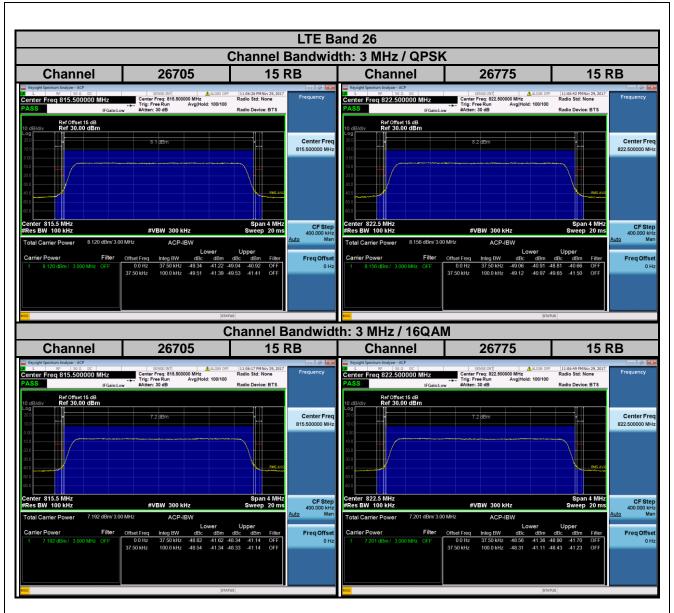




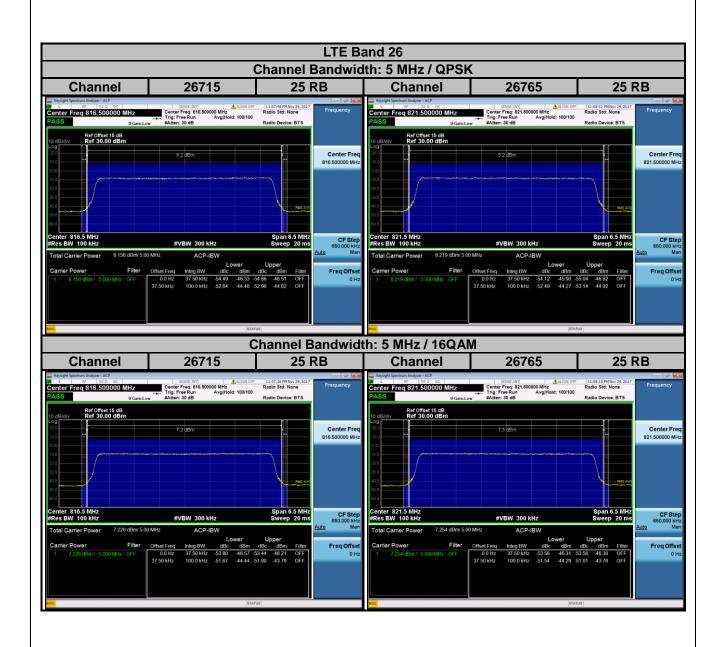




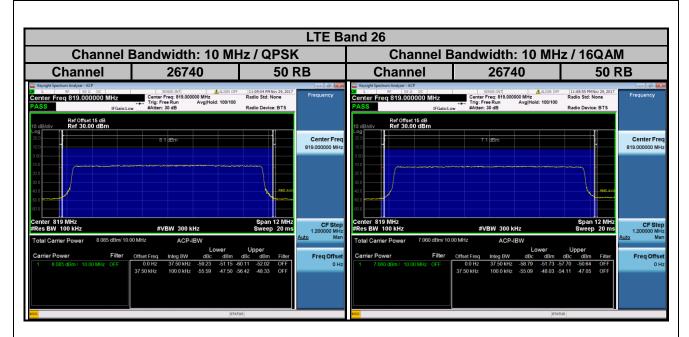












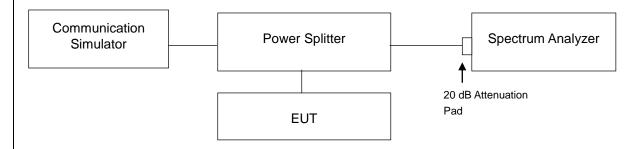


4.5 Conducted Spurious Emissions

4.5.1 Limits of Conducted Spurious Emissions Measurement

The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) by at least 43 +10 log10(P) dB. The limit of emission is equal to -13 dBm.

4.5.2 Test Setup

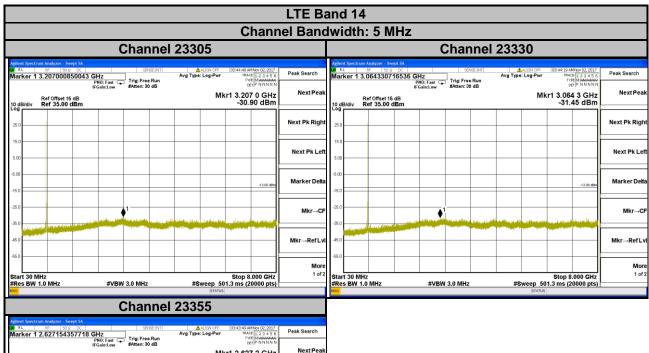


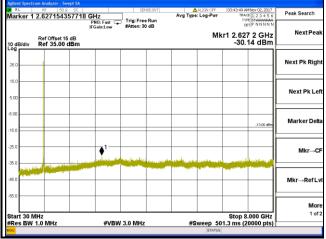
4.5.3 Test Procedure

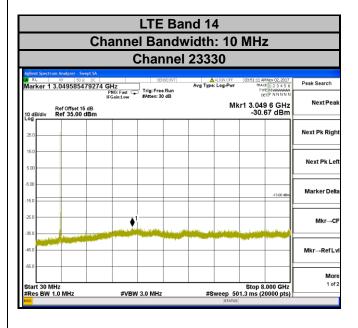
- a. The EUT makes a phone call to the communication simulator. All measurements were done at low, middle and high operational frequency range.
- b. Measuring frequency range is from 30 MHz to 9 GHz. 10 dB attenuation pad is connected with spectrum. RBW = 100 kHz and VBW = 300 kHz are used for conducted emission measurement.



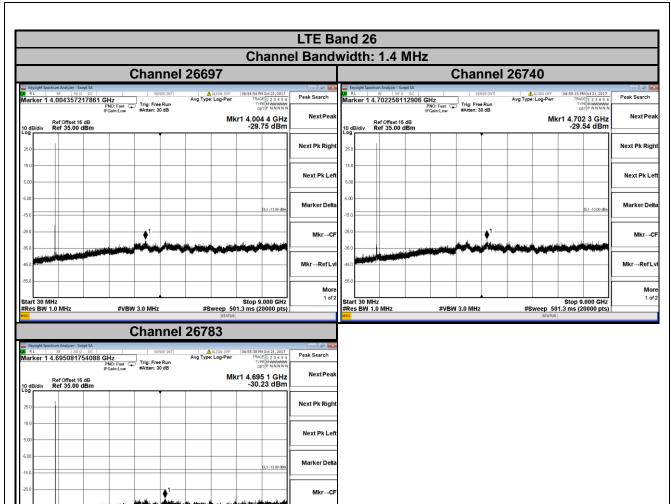
4.5.4 Test Results











Mkr→RefLv

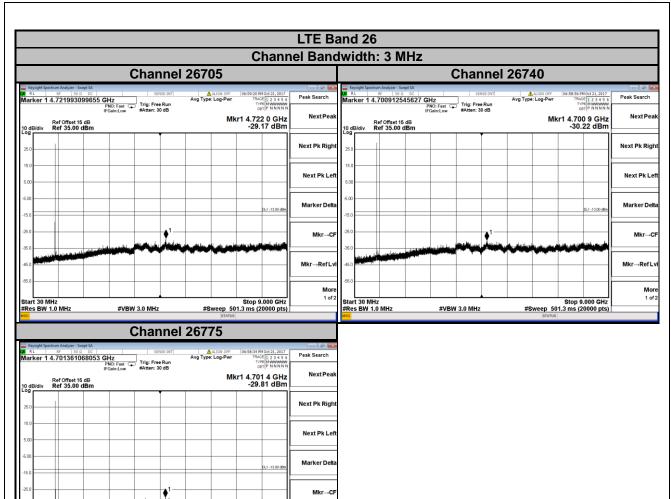
Stop 9.000 GHz #Sweep 501.3 ms (20000 pts)

Start 30 MHz #Res BW 1.0 MHz

#VBW 3.0 MHz

More 1 of 2





Mkr→RefLv

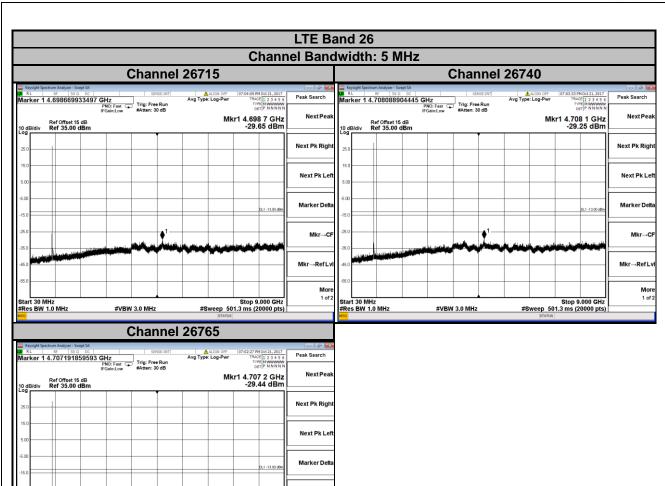
Stop 9.000 GHz #Sweep 501.3 ms (20000 pts)

Start 30 MHz #Res BW 1.0 MHz

#VBW 3.0 MHz

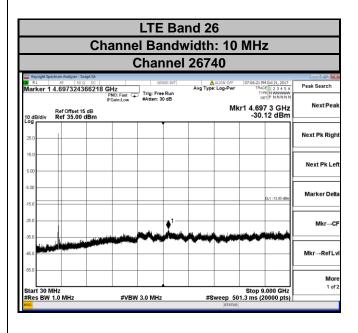
More 1 of 2





Mkr→RefL

Stop 9.000 GHz #Sweep 501.3 ms (20000 pts) More 1 of 2



#VBW 3.0 MHz

Start 30 MHz #Res BW 1.0 MHz



4.6 Radiated Emission Measurement

4.6.1 Limits of Radiated Emission Measurement

The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) by at least 43 +10 log10(P) dB. The limit of emission is equal to -13 dBm.

4.6.2 Test Procedure

- a. Substitution method is used for E.I.R.P measurement. In the semi-anechoic chamber, EUT placed on the 0.8 m (below or equal 1 GHz) and/or 1.5 m (above 1 GHz) height of Turn Table, rotated the table around 360 degrees to search the maximum radiation power and receiver antenna shall be rotated vertical and horizontal polarization and moved height from 1 m to 4 m to find the maximum polar radiated power. The "Read Value" is the spectrum reading the maximum power value.
- b. The substitution horn antenna is substituted for EUT at the same position and signals generator export the CW signal to the substitution antenna via a TX cable. Rotated the Turn Table and moved receiving antenna to find the maximum radiation power. Adjust output power level of S.G to get a Value of spectrum reading equal to "Read Value" of step a. Record the power level of S.G.
- c. EIRP = Output power level of S.G TX cable loss + Antenna gain of substitution horn.
- d. E.R.P power can be calculated form E.I.R.P power by subtracting the gain of dipole, E.R.P power = E.I.P.R power 2.15 dBi.

Note: The resolution bandwidth of spectrum analyzer is 1 MHz and the video bandwidth is 3 MHz.

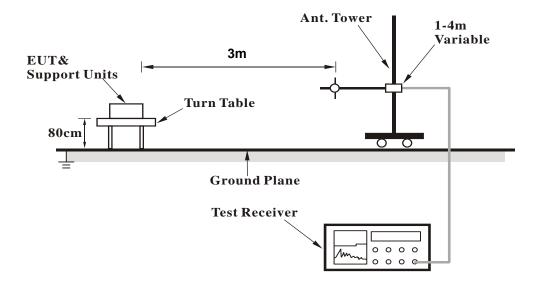
4.6.3 Deviation from Test Standard

No deviation.

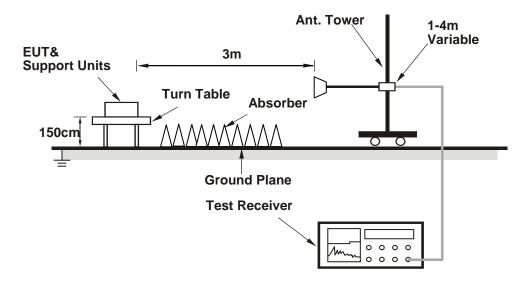


4.6.4 Test Setup

<Radiated Emission below or equal 1 GHz>



<Radiated Emission above 1 GHz>



For the actual test configuration, please refer to the attached file (Test Setup Photo).



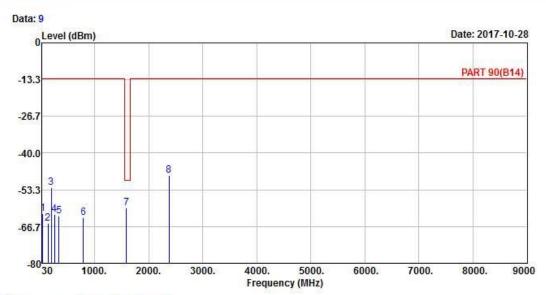
4.6.5 Test Results

LTE Band 14

Channel Bandwidth: 10 MHz / QPSK



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Site : 966 Chamber 5

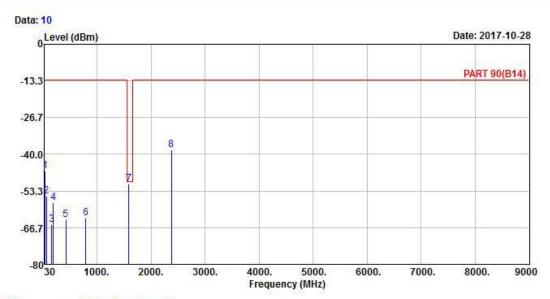
Condition: PART 90(B14) HORIZONTAL Remak : LTE Band 14 QPSK_10M_M-CH

	Freq	Level	Read Level	Limit Line	Over Limit	Factor	Remark
83	MHz	dBm	dBm	dBm	dB	dB	÷
1	39.18	-61.88	-61.98	-13.00	-48.88	0.10	Peak
2	135.30	-65.40	-56.73	-13.00	-52.40	-8.67	Peak
3	195.51	-52.52	-44.87	-13.00	-39.52	-7.65	Peak
4 5	257.07	-62.29	-56.16	-13.00	-49.29	-6.13	Peak
5	337.10	-62.88	-56.45	-13.00	-49.88	-6.43	Peak
6	792.80	-63.60	-64.36	-13.00	-50.60	0.76	Peak
7 pp	1586.00	-59.97	-45.07	-50.02	-9.95	-14.90	Peak
8	2379.00	-48.15	-37.71	-13.00	-35.15	-10.44	Peak





Bureau Veritas Consumer Products Services Ltd., Taoyuan Branch



Site : 966 Chamber 5

Condition: PART 90(B14) VERTICAL Remak : LTE Band 14 QPSK_10M_M-CH

	Freq	Level	Read Level	Limit	Over Limit	Factor	Remark
£	MHz	dBm	dBm	dBm	dB	dB	
1	39.45	-46.06	-46.70	-13.00	-33.06	0.64	Peak
2	64.83	-55.12	-47.09	-13.00	-42.12	-8.03	Peak
3	156.63	-65.64	-59.98	-13.00	-52.64	-5.66	Peak
4 5	190.38	-57.49	-50.40	-13.00	-44.49	-7.09	Peak
5	423.90	-63.67	-57.91	-13.00	-50.67	-5.76	Peak
6	787.90	-63.25	-64.02	-13.00	-50.25	0.77	Peak
7 pp	1586.00	-50.65	-35.75	-50.02	-0.63	-14.90	Peak
8	2379.00	-38.32	-27.88	-13.00	-25.32	-10.44	Peak

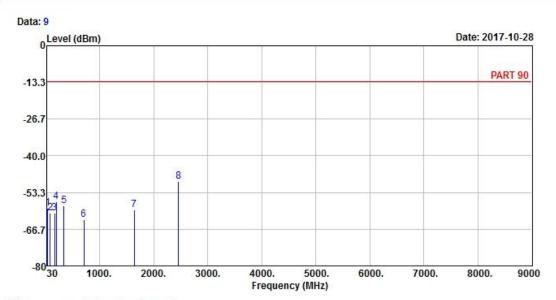


LTE Band 26

Channel Bandwidth: 10 MHz / QPSK



Bureau Veritas Consumer Products Services Ltd., Taoyuan Branch



Site : 966 Chamber 5 Condition: PART 90 HORIZONTAL

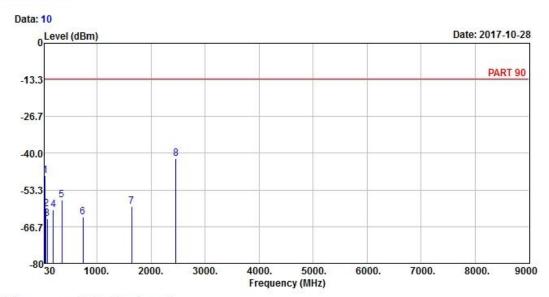
Remak : LTE Band 26 QPSK_10M_M-CH

	Freq	Level	Read Level		Over Limit	Factor	Remark
8 7.	MHz	dBm	dBm	dBm	dB	dB	
1	39.18	-59.16	-59.26	-13.00	-46.16	0.10	Peak
2	87.24	-60.94	-49.90	-13.00	-47.94	-11.04	Peak
3	170.94	-60.91	-55.21	-13.00	-47.91	-5.70	Peak
4	196.59	-56.66	-48.92	-13.00	-43.66	-7.74	Peak
5	342.00	-58.19	-51.83	-13.00	-45.19	-6.36	Peak
6	710.20	-63.28	-63.37	-13.00	-50.28	0.09	Peak
7	1638.00	-59.65	-44.86	-13.00	-46.65	-14.79	Peak
8 pp	2457.00	-49.23	-38.79	-13.00	-36.23	-10.44	Peak





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Site : 966 Chamber 5 Condition: PART 90 VERTICAL

Remak : LTE Band 26 QPSK_10M_M-CH

	Freq	Level	Read Level	Limit Line	Over Limit	Factor	Remark
8	MHz	dBm	dBm	dBm	dB	dB	
1	39.45	-48.26	-48.90	-13.00	-35.26	0.64	Peak
2	55.38	-60.14	-53.80	-13.00	-47.14	-6.34	Peak
3	81.03	-63.75	-52.84	-13.00	-50.75	-10.91	Peak
4	192.81	-60.45	-53.08	-13.00	-47.45	-7.37	Peak
4 5	348.30	-57.04	-50.77	-13.00	-44.04	-6.27	Peak
6	735.40	-63.21	-63.80	-13.00	-50.21	0.59	Peak
7	1638.00	-59.45	-44.66	-13.00	-46.45	-14.79	Peak
8 pp	2457.00	-42.01	-31.57	-13.00	-29.01	-10.44	Peak



5 Pictures of Test Arrangements								
Please refer to the attached file (Test Setup Photo).								



Appendix – Information on the Testing Laboratories

We, Bureau Veritas Consumer Products Services (H.K.) Ltd., Taoyuan Branch, were founded in 1988 to provide our best service in EMC, Radio, Telecom and Safety consultation. Our laboratories are FCC recognized accredited test firms and accredited according to ISO/IEC 17025.

If you have any comments, please feel free to contact us at the following:

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Hwa Ya EMC/RF/Safety

Tel: 886-3-3183232 Fax: 886-3-3270892

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Web Site: www.bureauveritas-adt.com

The address and road map of all our labs can be found in our web site also.

--- END ---

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